May 2005

Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock at the output.
- Input frequency: 25 MHz.
- Frequency outputs:
 - o 60 MHz (unmodulated)
 - o 2 x 48 MHz (unmodulated)
 - o 66.6 MHz (modulated): -1.7% down spread
- Modulation rate: 30 KHz.
- Supply voltage range: 3.3V ± 0.3V.
- Available in 8-pin SOIC Package.
- Commercial and Industrial Temperature range.
- RoHS Compliant

Product Description

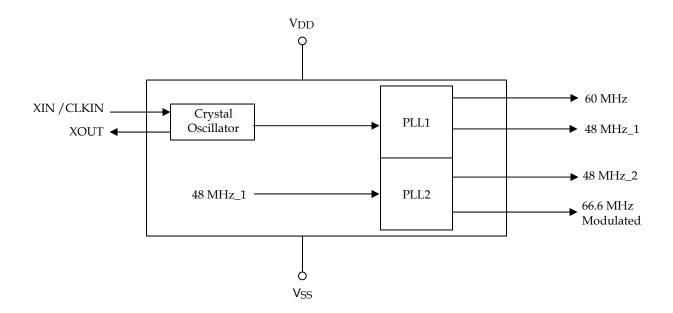
The ASM3P2111B is a versatile spread spectrum frequency modulator that reduces electromagnetic interference (EMI) at the clock source. The ASM3P2111B

allows significant system cost savings by reducing the number of circuit board layers and shielding that are required to pass EMI regulations. The ASM3P2111B modulates the output of PLL in order to spread the bandwidth of a synthesized clock, thereby decreasing the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most clock generators. Lowering EMI by increasing a signal's bandwidth is called spread spectrum clock generation.

Applications

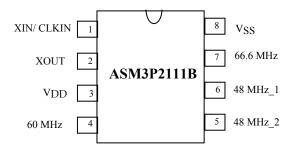
ASM3P2111B is targeted towards EMI management for high speed digital applications such as PC peripheral devices, consumer electronics and embedded controller systems.

Block Diagram





Pin Configuration



Pin Description

Pin #	Pin Name	Type	Description
1	XIN / CLKIN	I	Connection to crystal
2	XOUT	0	Connection to crystal
3	V_{DD}	Р	Power supply for the analog and digital blocks (+3.3V)
4	60 MHz	0	Clock output-1 60 MHz un-modulated
5	48 MHz_2	0	Clock output-2 48 MHz_2 un-modulated
6	48 MHz_1	0	Clock output-3 48 MHz_1 un-modulated
7	66.6 MHz	0	Clock output-4 66.6 MHz modulated
8	V _{SS}	Р	Ground to entire chip. Connect to System Ground



Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
V_{DD},V_{IN}	Voltage on any pin with respect to Ground	-0.5 to +7.0	V
T _{STG}	Storage temperature	-65 to +125	°C
T _A	Operating temperature	0 to 70	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
T_DV	Static Discharge Voltage (As per JEDEC STD 22- A114-B)	2	KV

Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.

Operating Conditions

Parameter	Symbol	Condition / Description	Min	Тур	Max	Unit
Supply Voltage	V_{DD}	$3.3V \pm 0.3V$	3	3.3	3.6	V
Crystal Resonator Frequency	F _{XIN}		25	-	-	MHz
Output Driver Load Capacitance	C_L		_	-	15	pF



rev 0.1

DC Electrical Characteristics

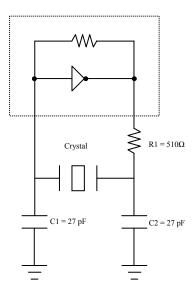
Parameter	Symbol	Conditions / Description	Min	Тур	Max	Unit		
Overall								
Supply Current, Dynamic	I _{DD}	V _{DD} =3.3V, F _{CLK} =25MHz, C _L =15pF	41	48	62	mA		
Supply Current, Static	I _{DDL}	V _{DD} = 3.3V, Clock Input = 0	20	25	35	mA		
All input pins								
High-Level Input Voltage	V _{IH}	V _{DD} =3.3V	2.0	-	V _{DD} +0.3	V		
Low-Level Input Voltage	V _{IL}	V _{DD} =3.3V	V _{SS} -0.3	-	0.8	V		
High-Level Input Current	I _{IH}		-1	-	1	μΑ		
Low-Level Input Current (pull-up)	I _{IL}		-20	-36	-80	μΑ		
High-Level Output Source Current	I _{xOH}	$V_{DD}=V (XIN) = 3.3V, V_{O}=0.4V$	-	3	-	mA		
Low-Level Output Sink Current	I _{xOL}	V _{DD} =3.3V, V (XIN)=V _O =2.5V	-	3	-	mA		
Clock Outputs								
High-Level Output Source Current	Іон	V _O =2.5V	-	-20	-	mA		
Low-Level Output Sink Current	I _{OL}	V _O =0.4V	-	23	-	mA		
Output Impedance	Z _{OH}	V _O =0.5V _{DD} ; output driving high Vo=0.5V _{DD} ; output driving low	-	29 27	-	Ω		

AC Electrical Characteristics

Parameter	Symbol	Conditions/ Description	Min	Тур	Max	Unit
Rise Time	t _r	$V_0 = 0.8V \text{ to } 2.0V;$ $C_L = 15pF$	300	800	900	pS
Fall Time	t _f	V _O = 2.0V to 0.8V; C _L = 15pF	360	800	900	pS
Clock Duty Cycle Ratio of pulse width (as measured from rising edge to next falling edge at V _{DD} /2) to one clock period - 55 %						%



Typical Crystal Oscillator Circuit



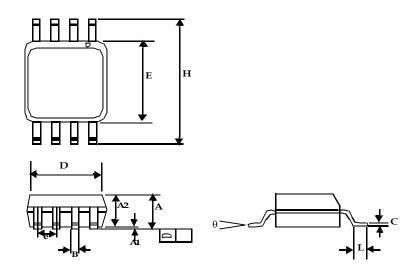
Typical Crystal Specifications

Fundamental AT cut parallel resonant crystal				
Nominal frequency	25 MHz			
Frequency tolerance	± 50 ppm or better at 25°C			
Operating temperature range	-25°C to +85°C			
Storage temperature	-40°C to +85°C			
Load capacitance	18pF			
Shunt capacitance	7pF maximum			
ESR	25 Ω			



Package Information

8-Pin SOIC Package



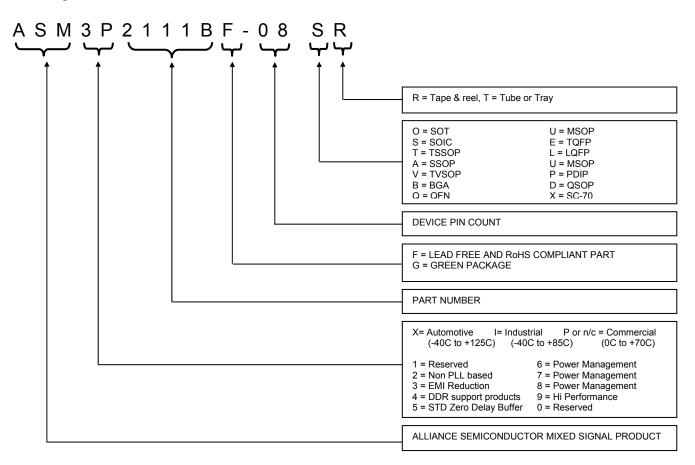
	Dimensions					
Symbol	Inc	hes	Millimeters			
	Min	Max	Min	Max		
A1	0.004	0.010	0.10	0.25		
Α	0.053	0.069	1.35	1.75		
A2	0.049	0.059	1.25	1.50		
В	0.012	0.020	0.31	0.51		
С	0.007	0.010	0.18	0.25		
D	0.193 BSC		4.90 BSC			
E	0.154 BSC		3.91 BSC			
е	0.050 BSC		1.27 BSC			
Н	0.236 BSC		6.00	BSC		
L	0.016	0.050	0.41	1.27		
θ	0°	8°	0°	8°		



rev 0.1 Ordering Codes

Part number	Marking	Package Configuration	Temperature Range
ASM3P2111BF-08ST	3P2111BF	8-pin SOIC TUBE, Pb Free	Commercial
ASM3P2111BF-08SR	3P2111BF	8-pin SOIC TAPE & REEL, Pb Free	Commercial
ASM3I2111BF-08ST	3I2111BF	8-pin SOIC TUBE, Pb Free	Industrial
ASM3I2111BF-08SR	3I2111BF	8-pin SOIC TAPE & REEL, Pb Free	Industrial
ASM3P2111BG-08ST	3P2111BG	8-pin SOIC TUBE, Green	Commercial
ASM3P2111BG-08SR	3P2111BG	8-pin SOIC TAPE & REEL, Green	Commercial
ASM3I2111BG-08ST	3I2111BG	8-pin SOIC TUBE, Green	Industrial
ASM3I2111BG-08SR	3l2111BG	8-pin SOIC TAPE & REEL, Green	Industrial

Ordering Information



Licensed under US patent #5,488,627, #6,646,463 and #5,631,920.



Alliance Semiconductor Corporation 2575, Augustine Drive, Santa Clara, CA 95054 Tel# 408-855-4900 Fax: 408-855-4999 www.alsc.com Copyright © Alliance Semiconductor All Rights Reserved Part Number: ASM3P2111B Document Version: v0.1

Note: This product utilizes US Patent # 6,646,463 Impedance Emulator Patent issued to Alliance Semiconductor, dated 11-11-2003

© Copyright 2003 Alliance Semiconductor Corporation. All rights reserved. Our three-point logo, our name and Intelliwatt are trademarks or registered trademarks of Alliance. All other brand and product names may be the trademarks of their respective companies. Alliance reserves the right to make changes to this document and its products at any time without notice. Alliance assumes no responsibility for any errors that may appear in this document. The data contained herein represents Alliance's best data and/or estimates at the time of issuance. Alliance reserves the right to change or correct this data at any time, without notice. If the product described herein is under development, significant changes to these specifications are possible. The information in this product data sheet is intended to be general descriptive information for potential customers and users, and is not intended to operate as, or provide, any guarantee or warrantee to any user or customer. Alliance does not assume any responsibility or liability arising out of the application or use of any product described herein, and disclaims any express or implied warranties related to the sale and/or use of Alliance products including liability or warranties related to fitness for a particular purpose, merchantability, or infringement of any intellectual property rights, except as express agreed to in Alliance's Terms and Conditions of Sale (which are available from Alliance). All sales of Alliance products are made exclusively according to Alliance's Terms and Conditions of Sale. The purchase of products from Alliance does not convey a license under any patent rights, copyrights; mask works rights, trademarks, or any other intellectual property rights of Alliance or third parties. Alliance does not authorize its products for use as critical components in life-supporting systems where a malfunction or failure may reasonably be expected to result in significant injury to the user, and the inclusion of Alliance products in such life-supporting systems implies that the manufacturer assumes all risk of such use and agrees to indemnify Alliance against all claims arising from such use.